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BCV64B PNP general-purpose double transistor Rev. 4 – 2 August 2010

Product data sheet

1. Product profile

1.1 General description

PNP general-purpose double transistor in a small SOT143B Surface-Mounted Device (SMD) plastic package.

Table 1.Product overview

| Type number | Package | | PNP complement | |
|-------------|---------|-------|----------------|--|
| | NXP | JEITA | | |
| BCV64B | SOT143B | - | BCV63B | |

1.2 Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 30 V and 6 V)
- AEC-Q101 qualified
- Small SMD plastic package

1.3 Applications

- General-purpose switching and amplification
- For use in Schmitt trigger applications

1.4 Quick reference data

Table 2. Quick reference data

| | quient rener entre auta | | | | | |
|------------------|---------------------------|---|---------|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Per trans | istor | | | | | |
| I _C | collector current | | - | - | -100 | mA |
| Transisto | or TR1 | | | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | -30 | V |
| h _{FE} | DC current gain | V _{CE} = –5 mV; I _C = –2 mA | 220 | - | 475 | |
| Transisto | or TR2 | | | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | -6 | V |
| h _{FE} | DC current gain | $V_{CE} = -700 \text{ V};$ $I_{C} = -2 \text{ mA}$ | [1] 220 | - | 475 | |

[1] Due to matched dies, h_{FE} values for TR2 are the same as for TR1.



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PNP general-purpose double transistor

2. Pinning information

| Table 3. | Pinning | | |
|----------|----------------------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | collector TR2 and base TR1 | | |
| 2 | collector TR1 | | |
| 3 | emitter TR1 and TR2 | | |
| 4 | base TR2 | | |

3. Ordering information

| Table 4. Orderi | ng informa | tion | |
|-----------------|------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BCV64B | - | plastic surface-mounted package; 4 leads | SOT143B |

4. Marking

| Table 5. Marking codes | |
|--------------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| BCV64B | *C6 |
| [1] * = -: made in Hong Kong | |

- * = p: made in Hong Kong
- * = t: made in Malaysia
- * = W: made in China

5. Limiting values

| Table 6. In accorda | Limiting values ance with the Absolute Maximum | Rating System (IEC | 60134). | | |
|------------------------|---|------------------------------|--------------|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| Per trans | istor | | | | |
| V_{EBO} | emitter-base voltage | open collector | - | -6 | V |
| I _C | collector current | | - | -100 | mA |
| I _{CM} | peak collector current | | - | -200 | mA |
| I _B | base current | | - | -100 | mA |
| Transisto | or TR1 | | | | |
| V _{CBO} | collector-base voltage | open emitter | - | -30 | V |
| V _{CEO} | collector-emitter voltage | open base | - | -30 | V |
| Transisto | or TR2 | | | | |
| V _{CBO} | collector-base voltage | open emitter | - | -6 | V |
| V _{CEO} | collector-emitter voltage | open base | - | -6 | V |
| Per devic | ;e | | | | |
| P _{tot} | total power dissipation | $T_{amb} \leq 25 ~^{\circ}C$ | <u>[1]</u> _ | 250 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

6. Thermal characteristics

| Table 7. | Thermal characteristics |
|----------|-------------------------|
|----------|-------------------------|

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|-------------|--------------|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> - | - | 500 | K/W |

[1] Device mounted on an FR4 PCB.

7. Characteristics

| Table 8. Characteristics |
|--------------------------|
|--------------------------|

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

| Per transistor I_{CBO} collector-base cut-off current $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$ $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$ - | -15 -5 | nA |
|--|-----------|-----|
| cut-off current $V_{CB} = -30 \text{ V}; \text{ I}_E = 0 \text{ A}; - T_j = 150 \text{ °C}$ | | |
| $v_{CB} = -30 \text{ v}, n_E = 0 \text{ A}, T_j = 150 \text{ °C}$ | -5 | |
| | | μA |
| $\label{eq:VCEsat} \begin{array}{c} \text{Collector-emitter} & \text{I}_{C} = -10 \text{ mA}; \\ \text{saturation voltage} & \text{I}_{B} = -0.5 \text{ mA} \end{array} \qquad -75$ | -300 | mV |
| V_{BEsat} base-emitter $I_{C} = -10$ mA; [2]700 saturation voltage $I_{B} = -0.5$ mA | - | mV |
| Transistor TR1 | | |
| h _{FE} DC current gain $V_{CE} = -5 V$; 220 - $I_C = -2 mA$ | 475 | |
| | -650 | mV |
| V_{BEsat} base-emitter $I_{C} = -100 \text{ mA};$ [2]850 saturation voltage $I_{B} = -5 \text{ mA}$ | - | mV |
| V_{BE} base-emitter voltage I_{C} = -2 mA; [3] -600 -650 V_{CE} = -5 V | -750 | mV |
| $I_{C} = -10 \text{ mA};$ [3] $V_{CE} = -5 \text{ V}$ | -820 | mV |
| f_{T} transition frequency V_{CE} = –5 V; 100 - I_{C} = –10 mA; f = 100 MHz | - | MHz |
| $ \begin{array}{cc} C_c & \mbox{ collector capacitance } & V_{CB} = -10 \ V; & - & 4 \\ & I_E = i_e = 0 \ A; \\ & f = 1 \ MHz \end{array} $ | - | pF |
| Transistor TR2 | | |
| h_{FE} DC current gain $V_{CE} = -700 \text{ mV};$ [1] 220 - $I_C = -2 \text{ mA}$ | 475 | |
| V_{CEsat} collector-emitter $I_{C} = -100 \text{ mA};$ 250 saturation voltage $I_{B} = -5 \text{ mA}$ | - | mV |
| V_{BE} base-emitter voltage $I_C = -2 \text{ mA};$ [3]700 $V_{CE} = -700 \text{ mV}$ | - | mV |

[1] Due to matched dies, h_{FE} values for TR2 are the same as for TR1.

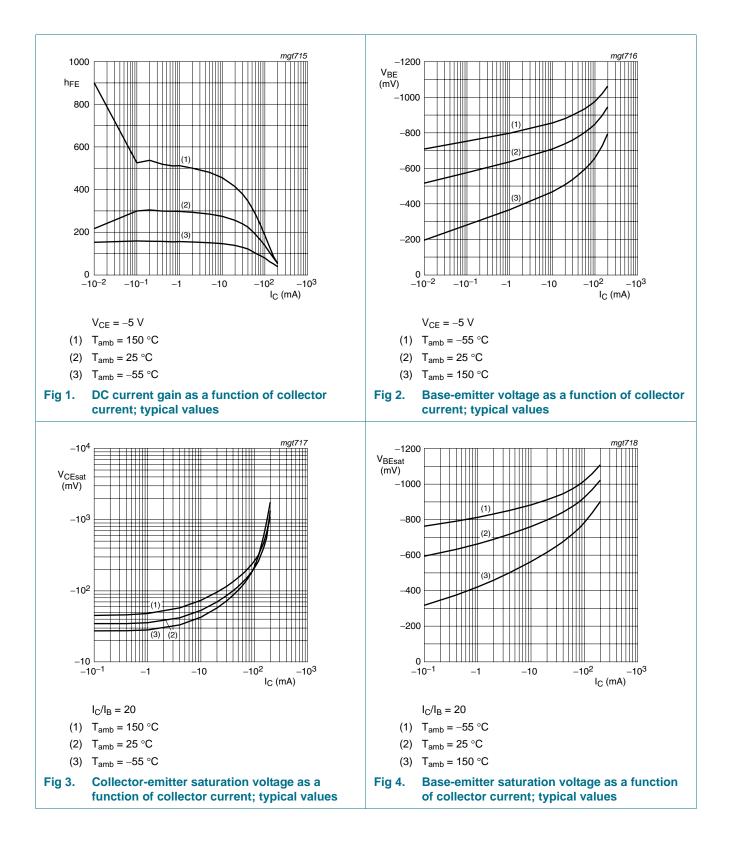
[2] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

[3] V_{BE} decreases by about 2 mV/K with increasing temperature.

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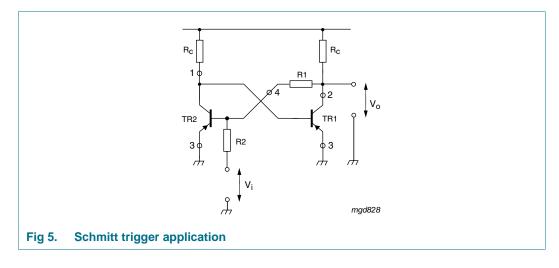
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PNP general-purpose double transistor



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8. Application information

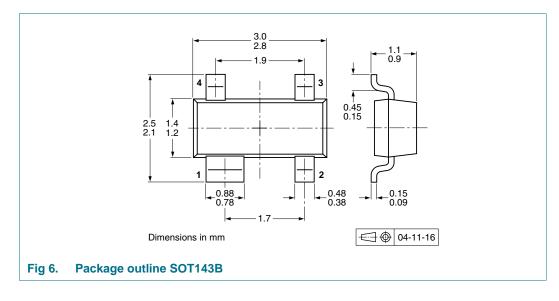


9. Test information

9.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

10. Package outline



11. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

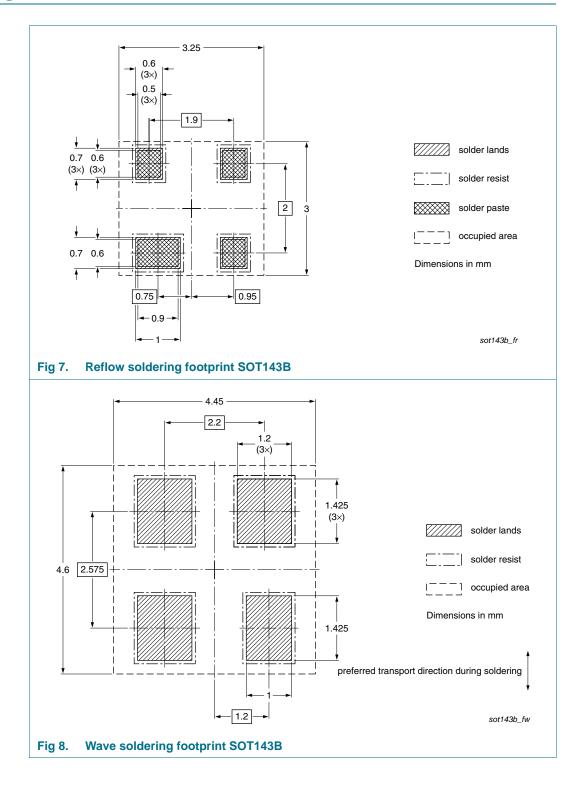
| Type number | Package | ge Description Packing quan | | quantity |
|-------------|---------|--------------------------------|------|----------|
| | | | 3000 | 10000 |
| BCV64B | SOT143B | 4 mm pitch, 8 mm tape and reel | -215 | -235 |

[1] For further information and the availability of packing methods, see <u>Section 15</u>.

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12. Soldering



13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|--|---|------------------------|----------------------|--|--|
| BCV64B v.4 | 20100802 | Product data sheet | - | BCV64B_3 | | |
| Modifications: | | of this data sheet has been of NXP Semiconductors. | redesigned to comply w | vith the new identit | | |
| | Legal texts | have been adapted to the r | new company name whe | ere appropriate. | | |
| | Section 1 " | Section 1 "Product profile": amended. | | | | |
| | Section 3 " | Ordering information": adde | d. | | | |
| | <u>Section 4 "Marking"</u>: updated. | | | | | |
| | • <u>Figure 1</u> , <u>2</u> , <u>3</u> and <u>4</u> : added. | | | | | |
| | Section 8 "Application information": added. | | | | | |
| | <u>Section 9 "Test information"</u>: added. | | | | | |
| | Figure 6: superseded by minimized package outline drawing. | | | | | |
| | Section 11 | "Packing information": adde | ed. | | | |
| | Section 12 | "Soldering": added. | | | | |
| | Section 14 | "Legal information": update | d. | | | |
| BCV64B_3 | 19990521 | Product specification | - | BCV64_CNV_2 | | |
| BCV64_CNV_2 | 19970310 | Product specification | _ | - | | |

14. Legal information

14.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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PNP general-purpose double transistor

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